

Product Summary

| Part # | V_{DS} | $R_{DS(on).typ}$ (@ $V_{GS}=10V$) | $R_{DS(on).typ}$ (@ $V_{GS}=4.5V$) | I_D |
|---------|----------|---------------------------------------|--|-------|
| EFM3402 | 30V | 32m Ω | 48m Ω | 4.2A |

Features

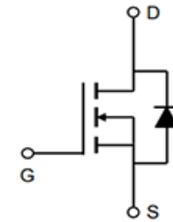
- Low $R_{DS(on)}$ @ $V_{GS}=10V$
- 4.5V Logic Level Control
- N Channel SOT23 Package
- Pb-Free, RoHS Compliant

Application

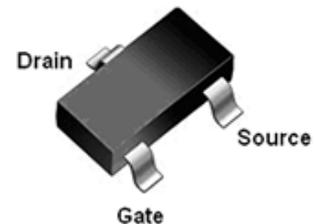
- DC-to-DC converters
- Power management in battery-driven portables
- Low-side load switch and charging switch for portable devices
- Switching circuits
- High-speed line driver

Ordering Information:

| | |
|---------------------------|-----------|
| Part NO. | EFM3402 |
| Marking | A29T |
| Packing Information | REEL TAPE |
| Basic ordering unit (pcs) | 3000 |



N-Channel MOSFET



SOT- 23



Absolute Maximum Ratings ($T_C=25^\circ C$)

| Parameter | Symbol | Limit | Unit |
|--|----------------|------------|------------|
| Drain-Source Voltage | V_{DS} | 30 | V |
| Gate-Source Voltage | V_{GS} | ± 12 | V |
| Drain Current-Continuous | I_D | 4.2 | A |
| Drain Current-Pulsed ^(Note 1) | I_{DM} | 20.4 | A |
| Maximum Power Dissipation | P_D | 1.5 | W |
| Operating Junction and Storage Temperature Range | T_J, T_{STG} | -55 To 150 | $^\circ C$ |

Thermal Characteristic

| | | | |
|---|-----------------|----|--------------|
| Thermal Resistance, Junction-to-Ambient ^(Note 2) | $R_{\theta JA}$ | 80 | $^\circ C/W$ |
|---|-----------------|----|--------------|

• Static Electrical Characteristics @ T_J = 25°C (unless otherwise stated)

| Parameter | Symbol | Condition | Min | Typ | Max | Unit |
|---|--------------|--|-----|------|-----------|------------|
| Off Characteristics | | | | | | |
| Drain-Source Breakdown Voltage | BV_{DSS} | $V_{GS}=0V I_D=250\mu A$ | 30 | -- | -- | V |
| Zero Gate Voltage Drain Current | I_{DSS} | $V_{DS}=30V V_{GS}=0V$ | -- | -- | 1 | μA |
| Gate-Body Leakage Current | I_{GSS} | $V_{GS}=\pm 12V V_{DS}=0V$ | -- | -- | ± 100 | nA |
| On Characteristics (Note 3) | | | | | | |
| Gate Threshold Voltage | $V_{GS(th)}$ | $V_{DS}=V_{GS} I_D=250\mu A$ | 0.5 | 0.8 | 1.2 | V |
| Drain-Source On-State Resistance | $R_{DS(ON)}$ | $V_{GS}=10V I_D=4A$ | -- | 32 | 42 | m Ω |
| | | $V_{GS}=4.5V I_D=3A$ | -- | 48 | 65 | m Ω |
| Dynamic Characteristics (Note 4) | | | | | | |
| Input Capacitance | C_{iss} | $V_{DS}=15V V_{GS}=0V$ $F=1.0MHz$ | -- | 240 | -- | PF |
| Output Capacitance | C_{oss} | | -- | 35 | -- | PF |
| Reverse Transfer Capacitance | C_{rss} | | -- | 30 | -- | PF |
| Switching Characteristics (Note 4) | | | | | | |
| Turn-on Delay Time | $t_{d(on)}$ | $V_{DD}=15V I_D=1A$ $V_{GS}=10V R_G=3.3\Omega,$ | -- | 4.4 | -- | nS |
| Turn-on Rise Time | t_r | | -- | 2.6 | -- | nS |
| Turn-Off Delay Time | $t_{d(off)}$ | | -- | 25.5 | -- | nS |
| Turn-Off Fall Time | t_f | | -- | 3.3 | -- | nS |
| Total Gate Charge | Q_g | $V_{DS}=15V I_D=4A$ $V_{GS}=4.5V$ | -- | 3.1 | -- | nC |
| Gate-Source Charge | Q_{gs} | | -- | 0.4 | -- | nC |
| Gate-Drain Charge | Q_{gd} | | -- | 1.3 | -- | nC |
| Drain-Source Diode Characteristics | | | | | | |
| Diode Forward Voltage (Note 3) | V_{SD} | $V_{GS}=0V I_S=4A$ | -- | 0.85 | 1.2 | V |
| Diode Forward Current (Note 2) | I_S | | -- | -- | 4 | A |

Notes:

- ① Pulse width limited by maximum allowable junction temperature
- ② Pulse test ; Pulse width $\leq 300\mu s$, duty cycle $\leq 2\%$.

• Typical Characteristics

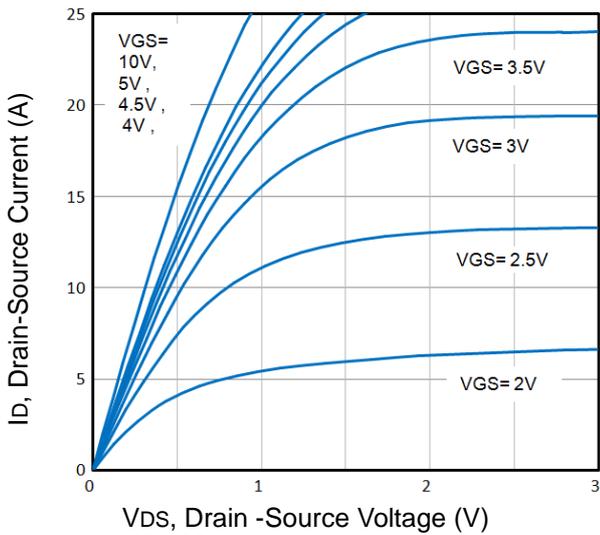


Fig1. Typical Output Characteristics

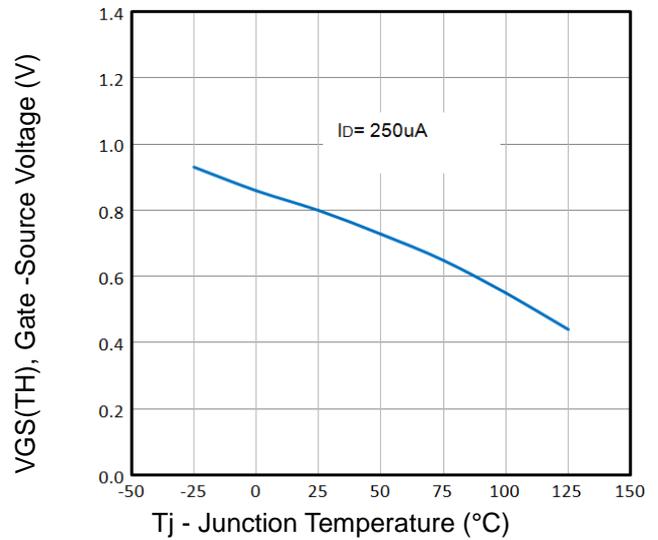


Fig2. Normalized Threshold Voltage Vs. Temperature

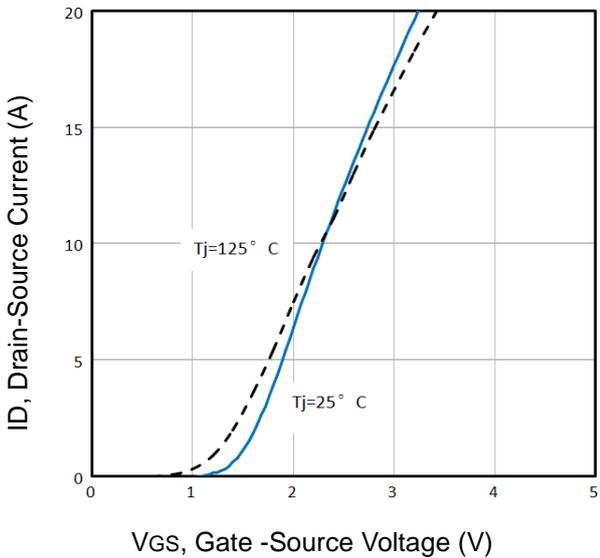


Fig3. Typical Transfer Characteristics

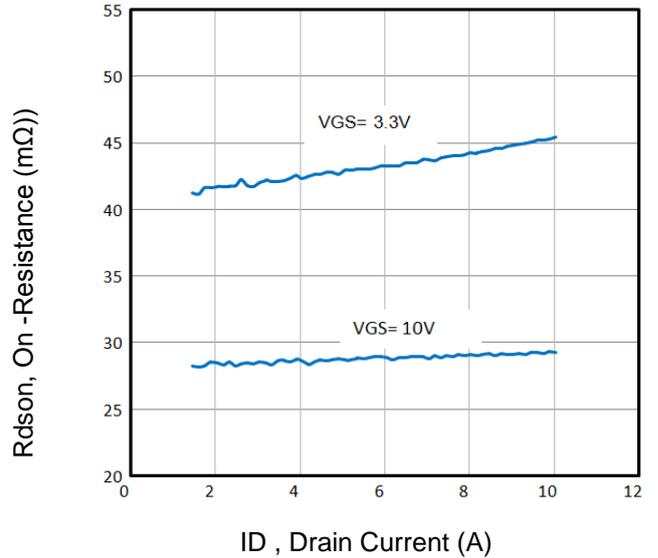


Fig4. On-Resistance vs. Drain Current and Gate

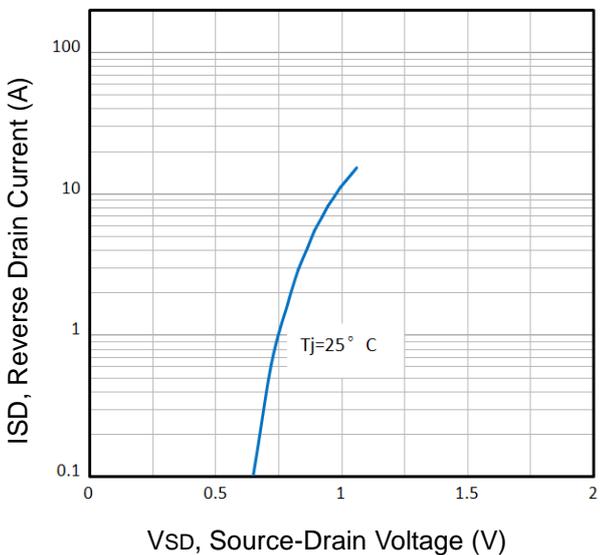


Fig5. Typical Source-Drain Diode Forward Voltage

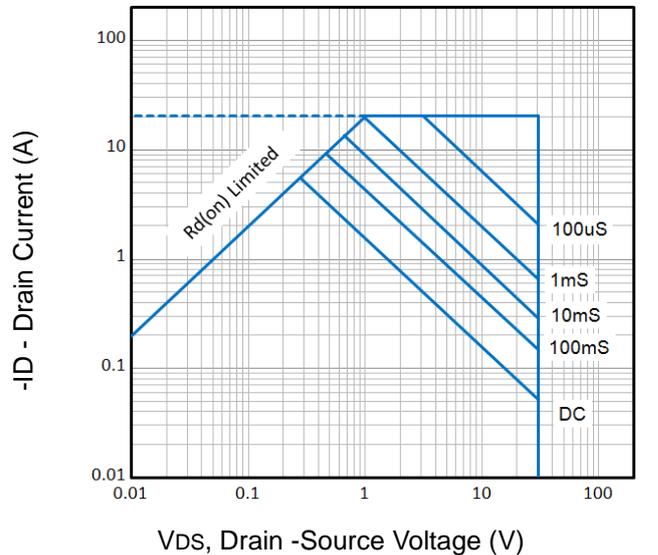


Fig6. Maximum Safe Operating Area

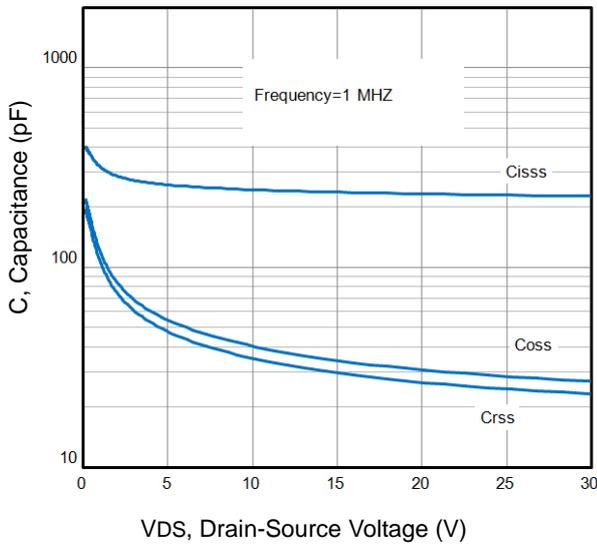


Fig7. Typical Capacitance Vs. Drain-Source Voltage

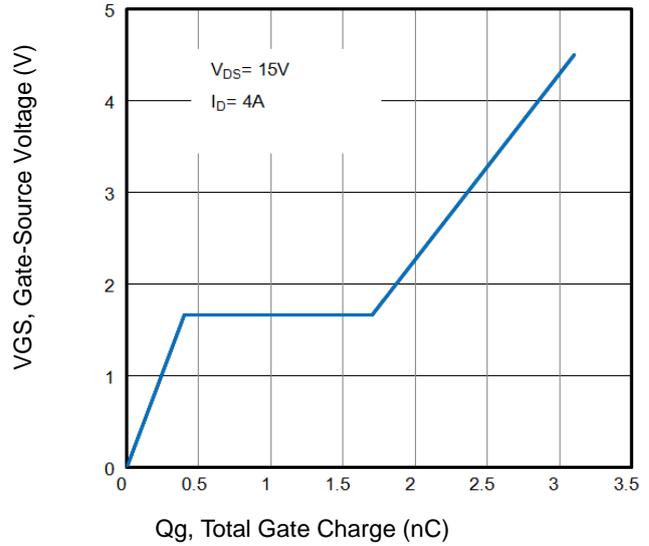


Fig8. Typical Gate Charge Vs. Gate-Source Voltage

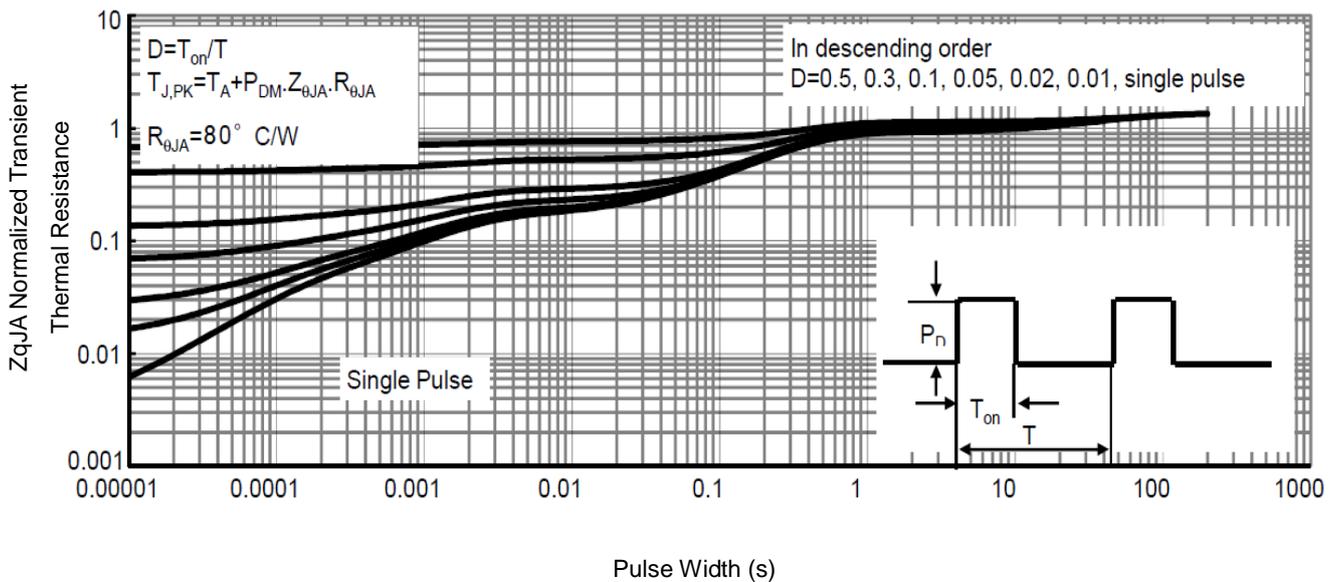


Fig9. Normalized Maximum Transient Thermal Impedance

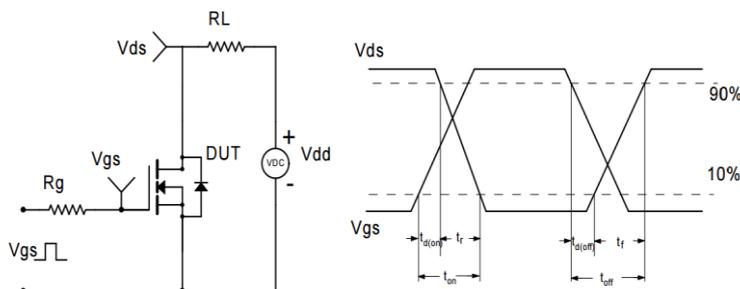
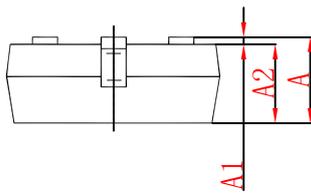
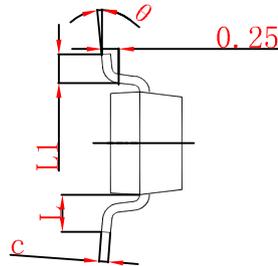
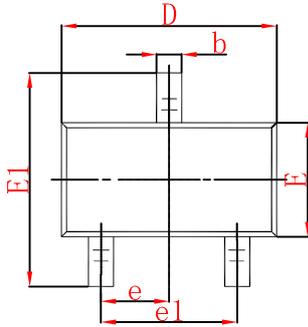
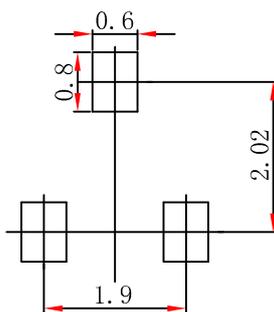


Fig10. Switching Time Test Circuit and waveforms

SOT-23 Package Outline Dimensions



| Symbol | Dimensions In Millimeters | | Dimensions In Inches | |
|--------|---------------------------|-------|----------------------|-------|
| | Min | Max | Min | Max |
| A | 0.900 | 1.150 | 0.035 | 0.045 |
| A1 | 0.000 | 0.100 | 0.000 | 0.004 |
| A2 | 0.900 | 1.050 | 0.035 | 0.041 |
| b | 0.300 | 0.500 | 0.012 | 0.020 |
| c | 0.080 | 0.150 | 0.003 | 0.006 |
| D | 2.800 | 3.000 | 0.110 | 0.118 |
| E | 1.200 | 1.400 | 0.047 | 0.055 |
| E1 | 2.250 | 2.550 | 0.089 | 0.100 |
| e | 0.950 TYP | | 0.037 TYP | |
| e1 | 1.800 | 2.000 | 0.071 | 0.079 |
| L | 0.550 REF | | 0.022 REF | |
| L1 | 0.300 | 0.500 | 0.012 | 0.020 |
| θ | 0° | 8° | 0° | 8° |



Note:

1. Controlling dimension: in millimeters.
2. General tolerance: $\pm 0.05\text{mm}$.
3. The pad layout is for reference purposes only.